NREL

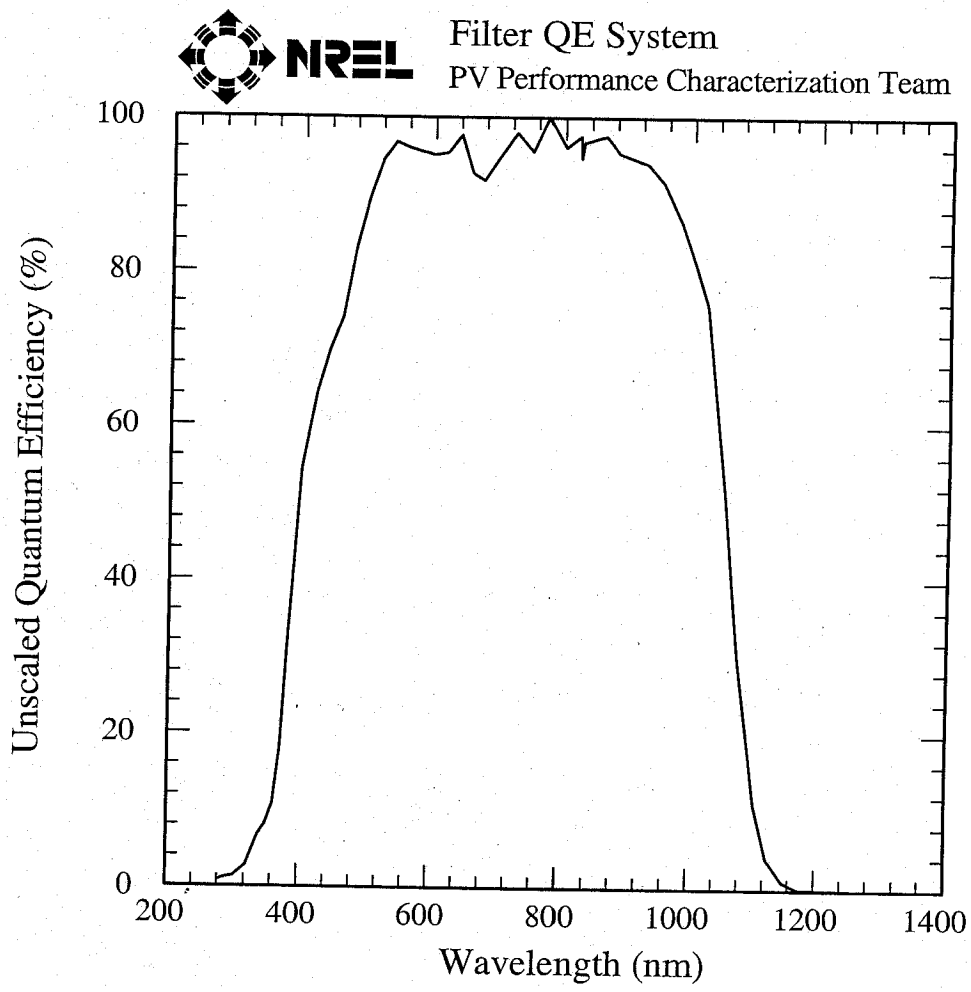
CdS/Cu(In,Ga)Se_2 Cell

Device ID: C1812-11 #3

Aug 17, 2004 1:47 PM

Device Temperature: 25.0 ± 1 °C

Device Area: 0.4090 cm^2



Voltage Bias: 0.0 V

Light bias for 13.7 mA

Light Bias region area: 0.4090 cm^2

Light Bias Density: 33.40 mA/cm^2

J_{sc} Estimate:

J_{sc} (Global) = 36.9 mA/cm^2